

# **Electrical Properties of Matter**

Fields and Waves

EE 6316

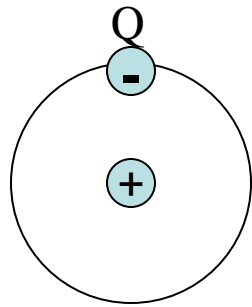
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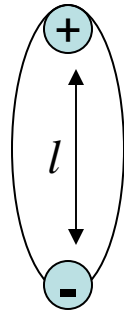
# Topics:

- Review of Dipole, Polarization ,Susceptibility etc in isotropic medium
- Classical Harmonic Oscillator Model
  - Abraham Lorentz Equation
  - Damping
  - Dispersion plots
- Application of the model : some examples
- Plasma
- Dielectric behavior in anisotropic medium
  - Permittivity tensor
  - Example: Modulator

# Review



No field



External field

$$p_i = Ql$$

$$\vec{D} = \epsilon_0 \vec{E} + \vec{P} = \epsilon_0 (1 + \chi_e) \vec{E} = \epsilon_0 \epsilon_r \vec{E} = \epsilon \vec{E}$$

where

$$\chi_e = \frac{1}{\epsilon_0} \frac{\vec{P}}{\vec{E}} \quad \vec{P} = \lim_{\Delta V \rightarrow 0} \sum_i \frac{P_i}{\Delta V}$$

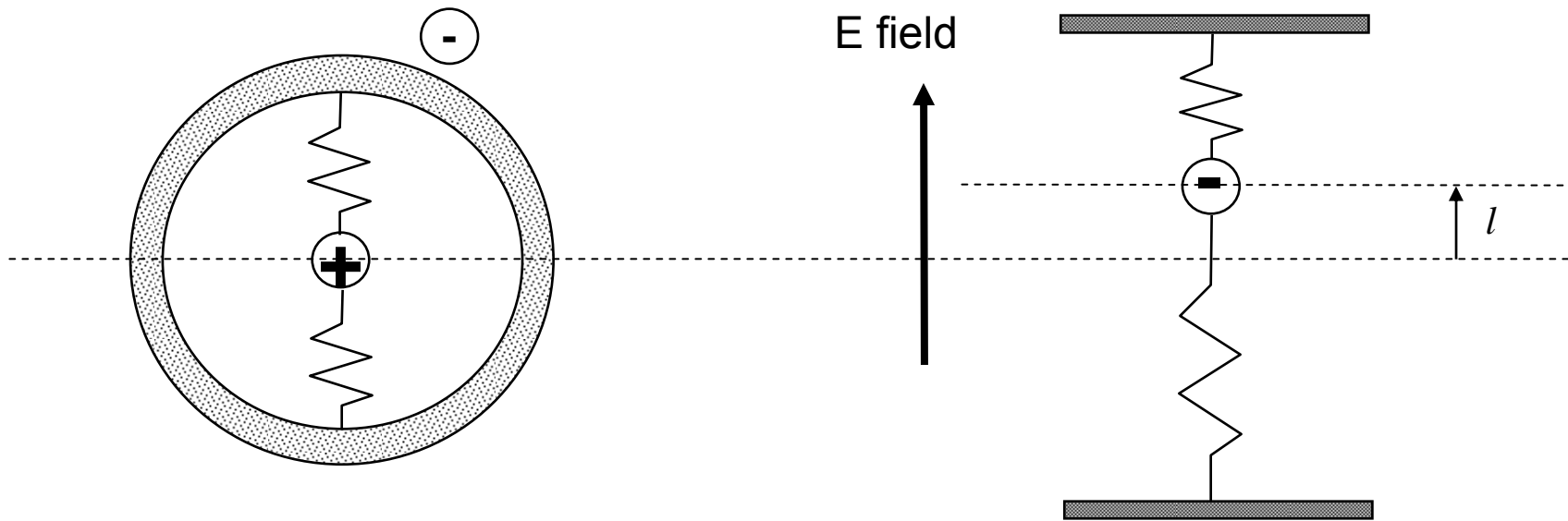
In terms of molecular polarizability,  $\alpha$

$$\vec{P} = N \alpha \vec{E}_{local}$$

$\alpha$  has contribution due to electronic, ionic and permanent dipole polarization

# Classical Electron Oscillator (CEO) Model

- electron cloud is modeled as a spring mass system, with attractive electric force between nucleus and electron cloud as the spring providing the restoring force



# Mechanical Equivalent model of CEO

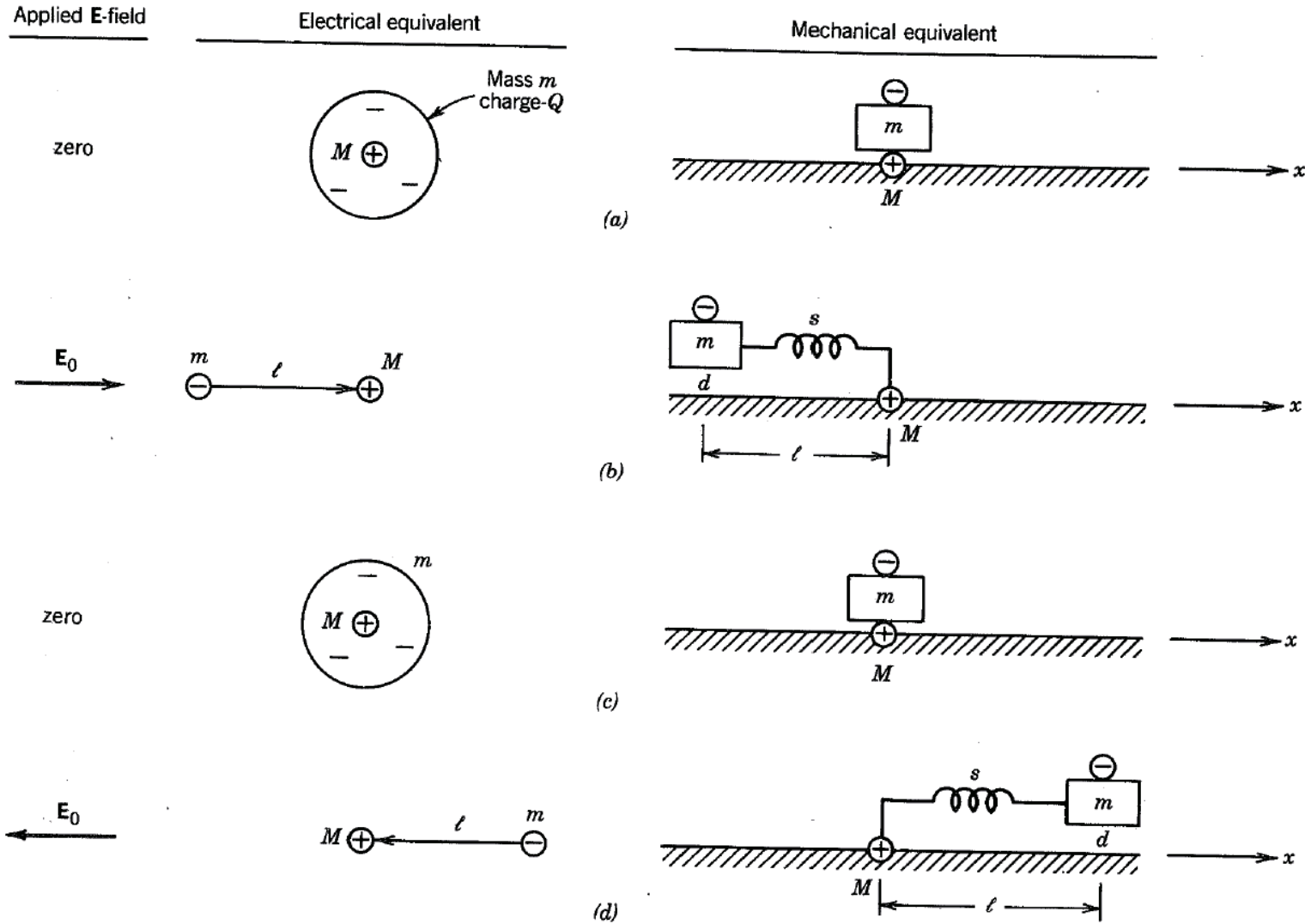


FIGURE 2-16 Electrical and mechanical equivalents of a typical atom in the absence of and under an applied electric field.

# Mathematical development of CEO Model

In the presence of an applied electric field: Abraham Lorentz Equation

$$m \frac{d^2 l}{dt^2} + d \frac{dl}{dt} + sl = Q \vec{E}(t) = Q \vec{E}_0 e^{j\omega t}$$

d: Damping coefficient

$$\Rightarrow \frac{d^2 l}{dt^2} + 2\alpha \frac{dl}{dt} + \omega_0^2 l = \frac{Q}{m} \vec{E}_0 e^{j\omega t}$$

s: spring constant

where

$$\alpha = \frac{d}{2m}$$

$$\omega_0 = \sqrt{\frac{s}{m}} \quad \text{:Resonant frequency}$$

$$l_{ss} = l_0 e^{j\omega t} = \frac{\frac{Q}{m} \vec{E}_0 e^{j\omega t}}{(\omega_0^2 - \omega^2) + j\omega \left( \frac{d}{m} \right)}$$

Steady state solution

# CEO Model :Damping Conditions

Condition	Classification of Solution
1) $\alpha > \omega_0$	overdamped
2) $\alpha = \omega_0$	Critically damped
3) $\alpha < \omega_0$	Underdamped

# Frequency dependent dielectric response: Dispersion

Polarization:  $\vec{P} = \frac{N \left( \frac{Q_2}{m} \right) \vec{E}}{(\omega_0^2 - \omega^2) + j\omega \left( \frac{d}{m} \right)}$

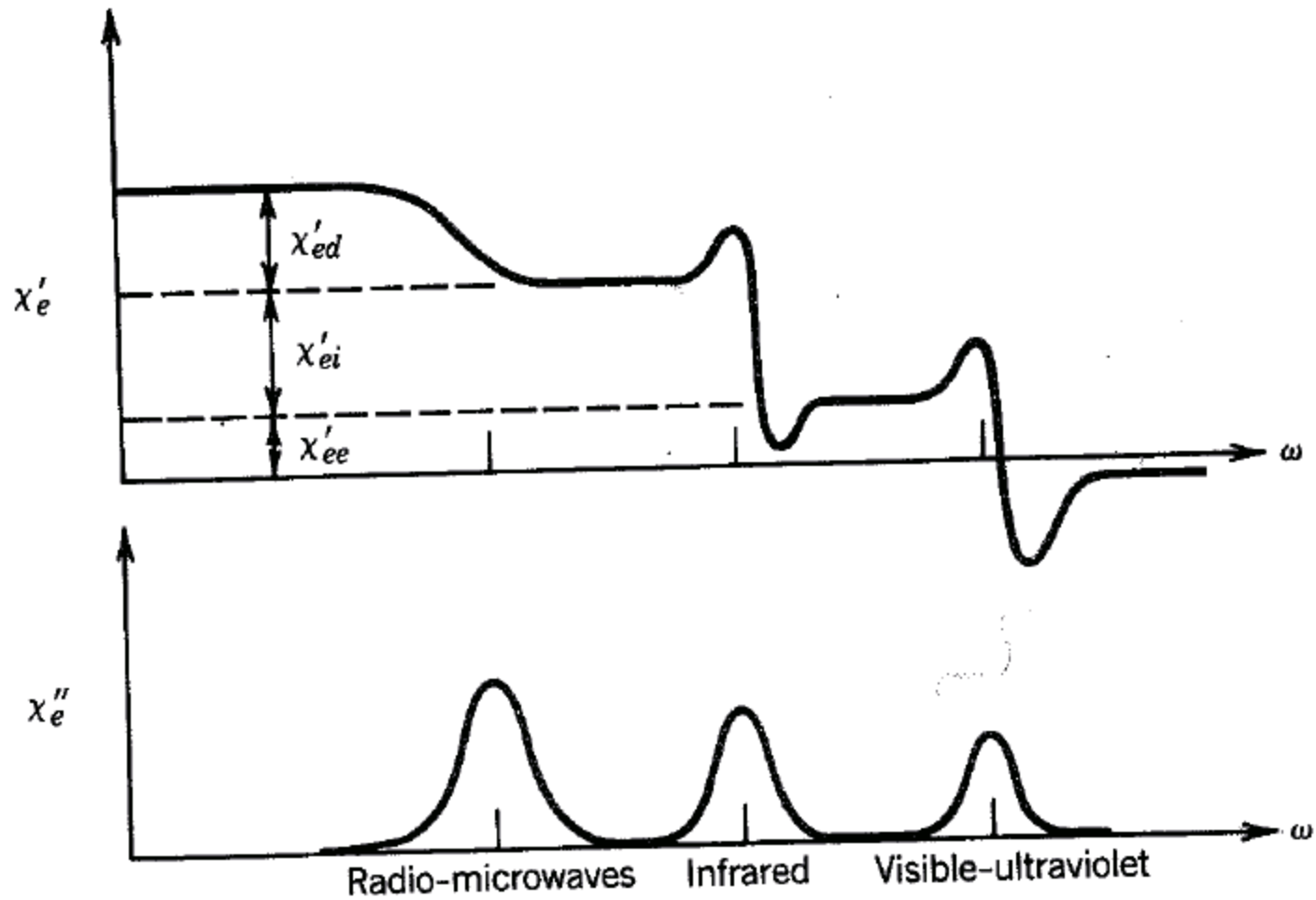
Permittivity:  $\epsilon = \epsilon_0 + \frac{\vec{P}}{\vec{E}} = \epsilon_0 + \frac{N \left( \frac{Q_2}{m} \right)}{(\omega_0^2 - \omega^2) + j\omega \left( \frac{d}{m} \right)} = \text{Re}(\epsilon) - j \text{Im}(\epsilon)$

Dispersion Relation of Permittivity

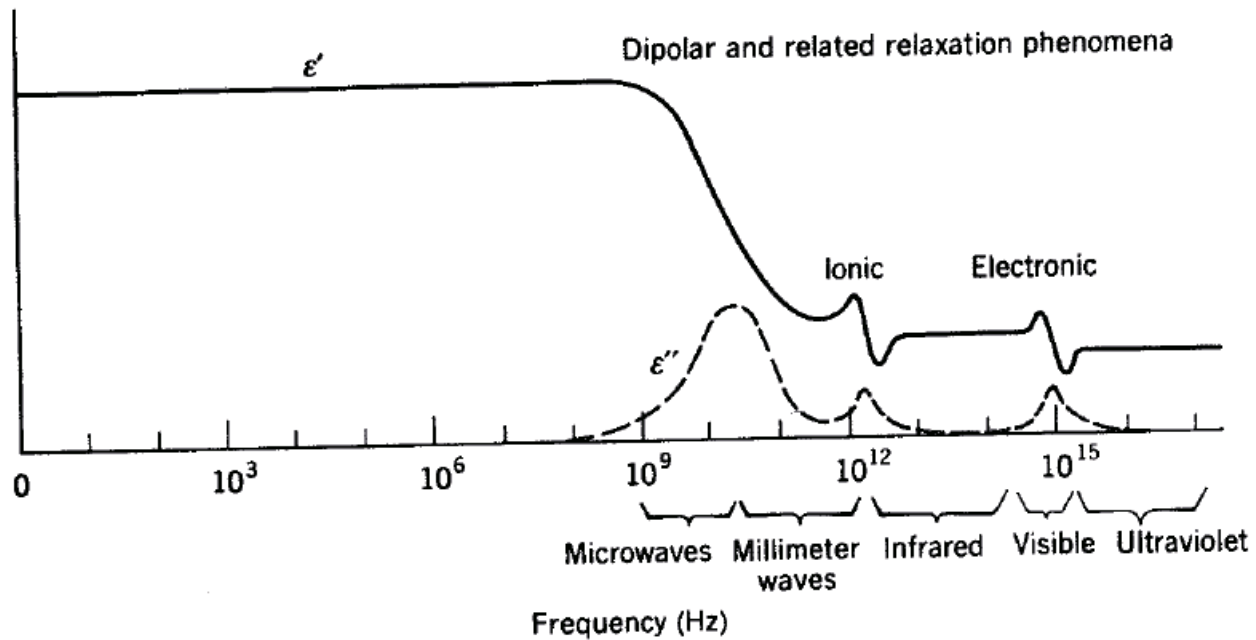
Similar relationship for relative permittivity hence refractive index can be derived. The real and imaginary parts of refractive index are related to each other through Kramers-Kronig relationship.



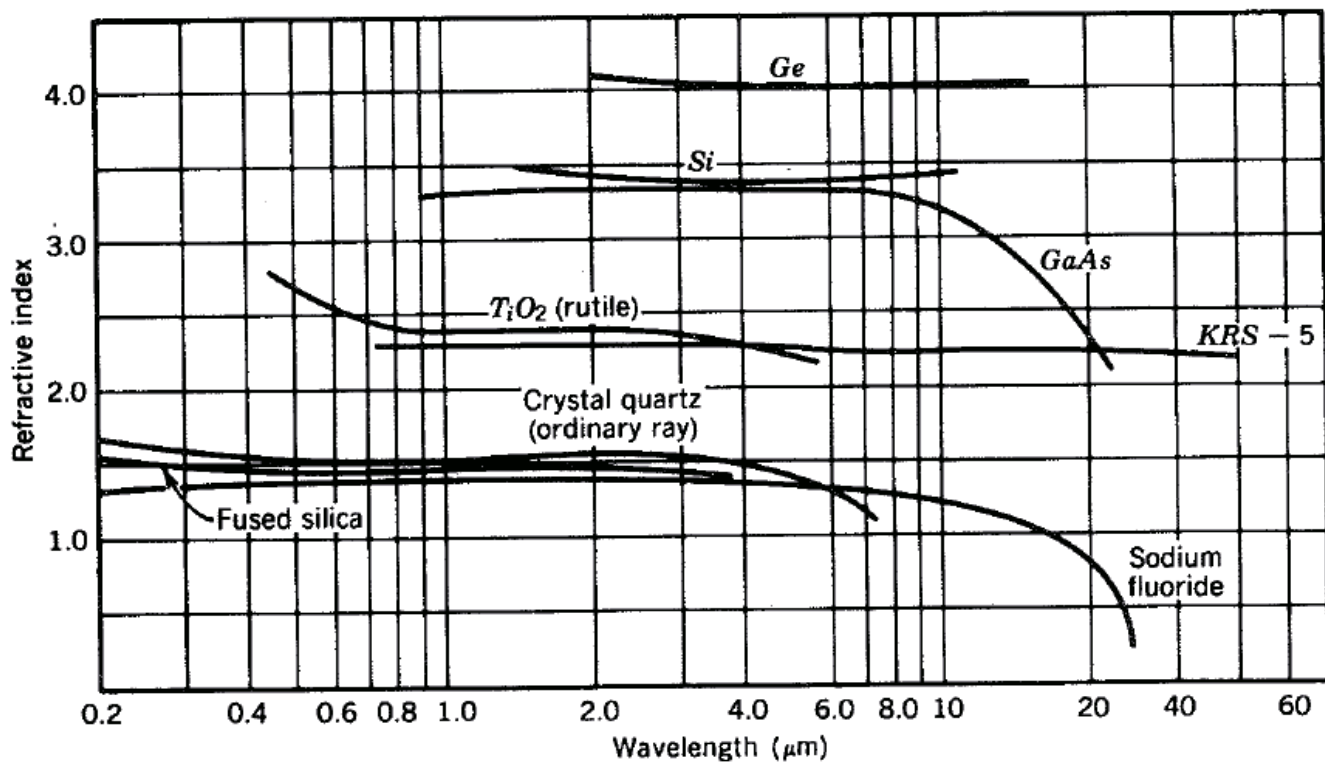
# Dispersion Plots



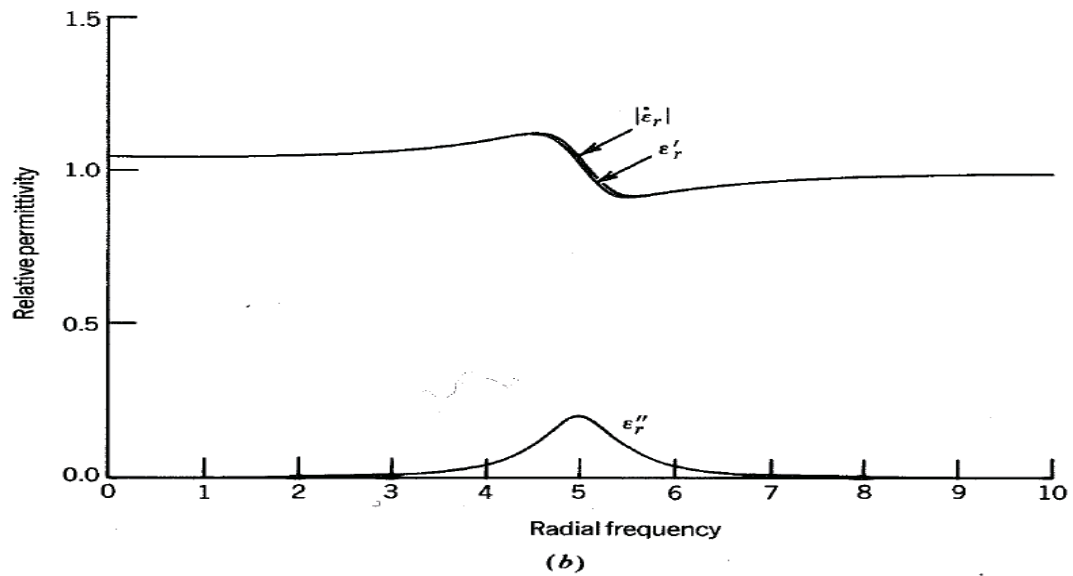
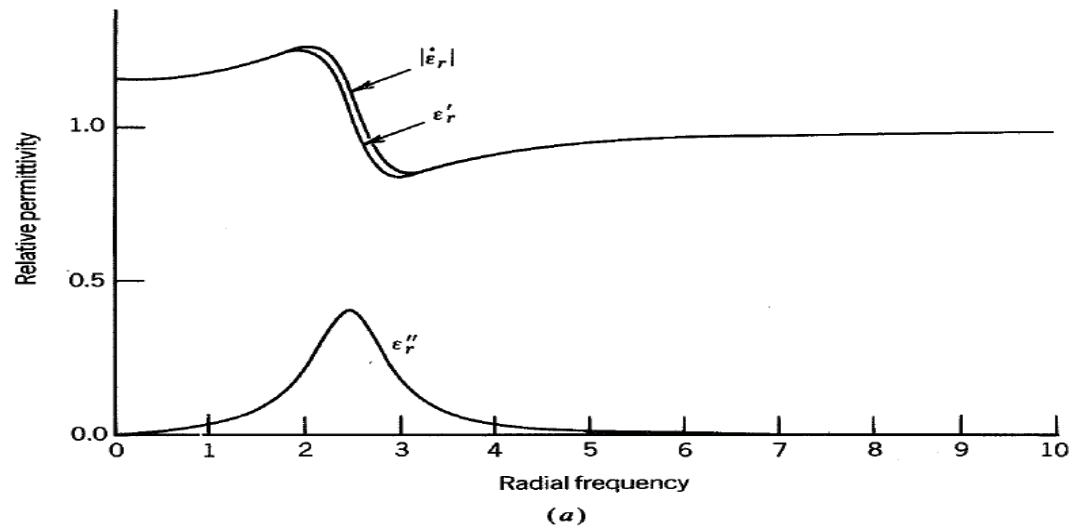
**FIGURE 2-18** Electric susceptibility (real and imaginary) variations as a function of frequency for a typical dielectric.



**Fig. 13.2a** Frequency response of permittivity and loss factor for a hypothetical dielectric showing various contributing phenomena.



**FIG. 13.2b** Refractive index versus wavelength for several materials with useful values of optical and infrared transparency. Data from *American Institute of Physics Handbook*.<sup>6</sup>



**FIGURE 2-19** Typical frequency variations of real and imaginary parts of relative permittivity of dielectrics. (a)  $N_e Q^2 / \epsilon_0 m = 1$ ,  $d/m = 1$ ,  $\alpha / \omega_0 = 1/5$ ,  $\omega_0 = 2.5$ . (b)  $N_e Q^2 / \epsilon_0 m = 1$ ,  $d/m = 1$ ,  $\alpha / \omega_0 = 1/10$ ,  $\omega_0 = 5$ .

# Application of CEO Model: Example

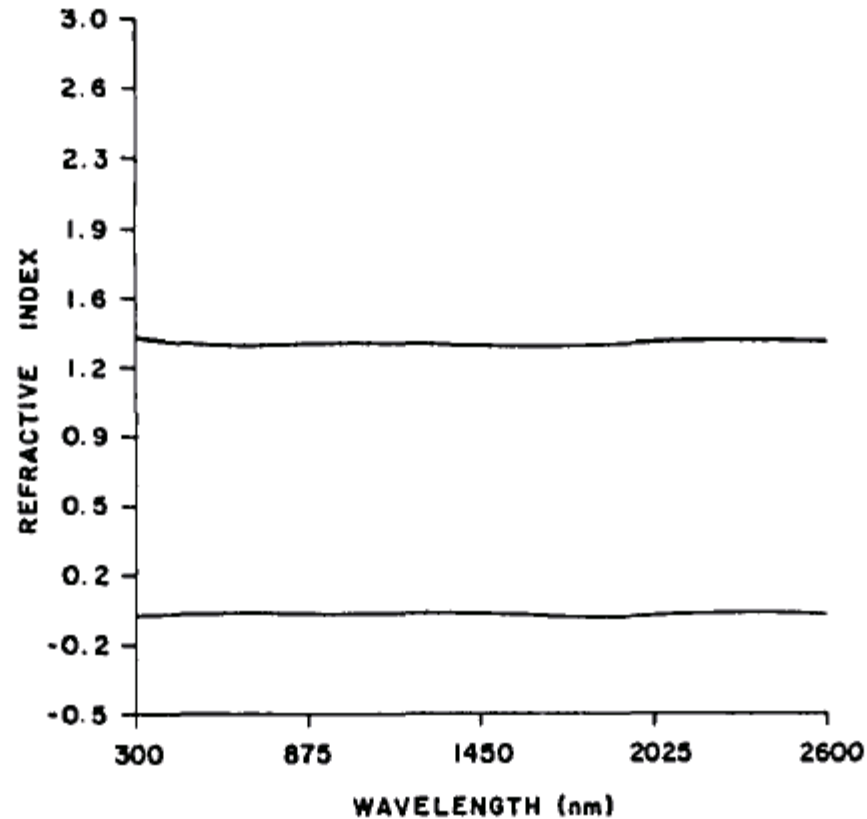


Fig. 5. Real and imaginary parts of the refractive index for MgF<sub>2</sub> calculated from the best-fitted parameters from two contributing oscillators.

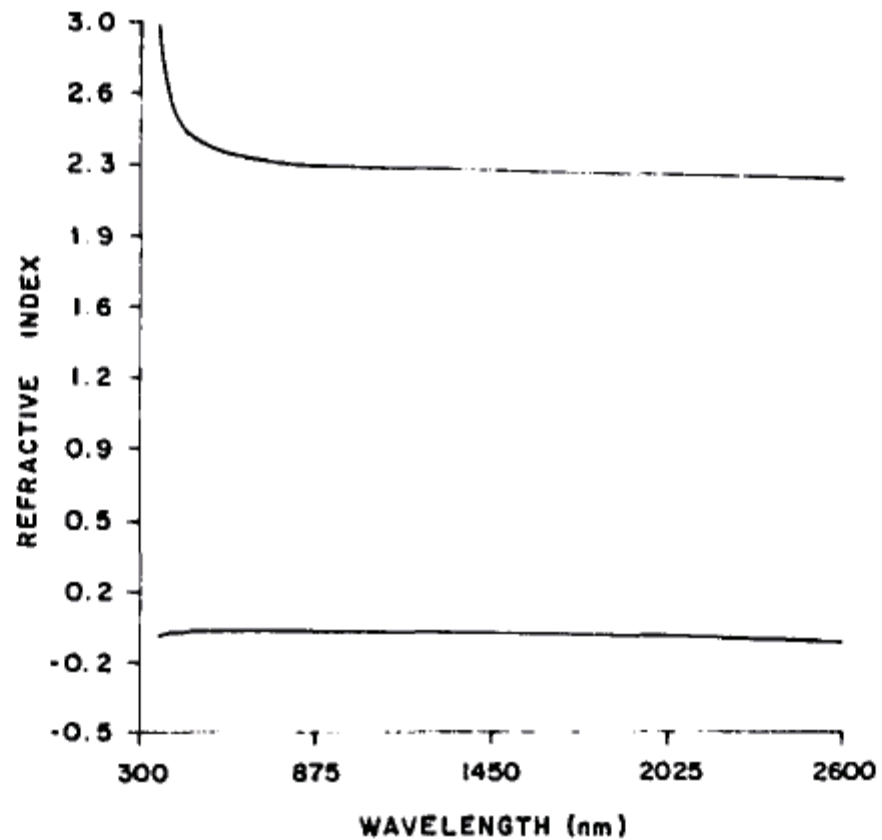


Fig. 6. Complex refractive index for ZnS. The dispersion is higher for the UV region. Two oscillators contribute to this calculation.

# Further Application of CEO Model

- This model can be extended to model optical processes in semiconductors
  - Spontaneous and Stimulated emission
  - Rabi Oscillation
  - Collision Broadening
  - Radiative lifetimes etc

# Plasma

- Plasma is a sea of free electrons in a background of positive ions of same density.
- Due to existence of free electrons, they are very conductive.
- Plasma response to electrical field is very strong too



# Dynamics of Plasma

- Motion of free electrons is governed by collision frequency  $f$

$$m \frac{d\vec{v}}{dt} = -e\vec{E} - m\vec{v}f$$

For sinusoidal variation:

$$\Rightarrow \vec{v} = -\frac{e\vec{E}}{m(f + j\omega)}$$

Convection Current:

$$\vec{J} = -ne\vec{v} = \frac{ne^2\vec{E}}{m(f + j\omega)}$$

Inserting in Curl Eqn:

$$\nabla \times \vec{H} = j\omega\epsilon_0\vec{E} + \vec{J} = j\omega\epsilon_0\vec{E} + \frac{ne^2\vec{E}}{m(f + j\omega)}$$

$$= j\omega \left[ \left( \epsilon_0 - \frac{ne^2}{m(f^2 + \omega^2)} \right) - j \frac{ne^2 f}{m\omega(f^2 + \omega^2)} \right] \vec{E}$$

Real Part
Imaginary part=0 as  $f \rightarrow 0$

# Plasma Frequency

$$\varepsilon = \varepsilon_0 - \frac{ne^2}{m\omega^2} = \varepsilon_0 \left( 1 - \frac{\omega_p^2}{\omega^2} \right)$$

*where*

Plasma frequency  $\omega_p = \sqrt{\frac{ne^2}{\varepsilon_0 m}}$

Permittivity is negative for frequencies below plasma frequency. Physically this means wave is reflected off of plasma and attenuated inside.

# Anisotropic Media: Dielectric tensors

$$\left[ \vec{D} \right] = [\boldsymbol{\varepsilon}] \left[ \vec{E} \right]$$

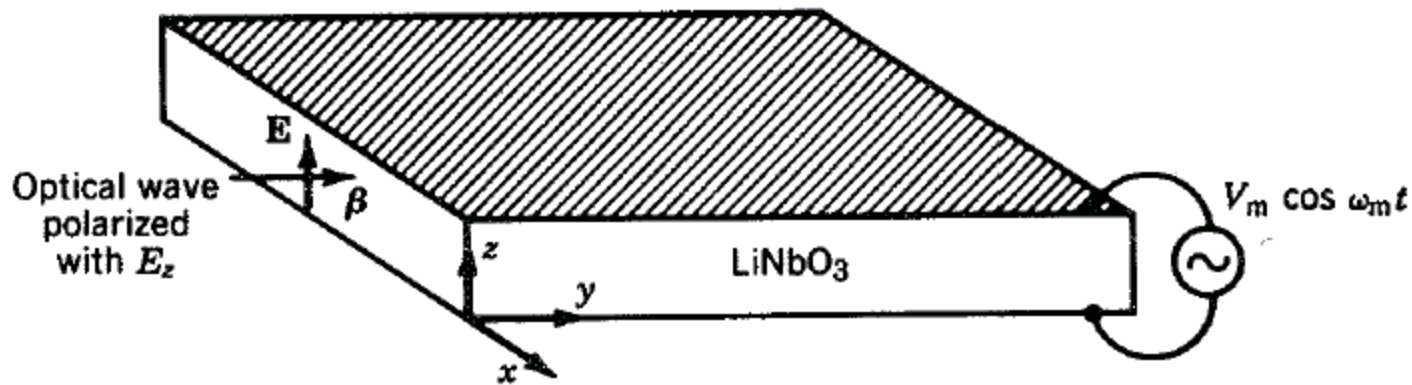
$$\begin{bmatrix} D_x \\ D_y \\ D_z \end{bmatrix} = \begin{bmatrix} \varepsilon_{xx} & \varepsilon_{xy} & \varepsilon_{xz} \\ \varepsilon_{yx} & \varepsilon_{yy} & \varepsilon_{yz} \\ \varepsilon_{zx} & \varepsilon_{zy} & \varepsilon_{zz} \end{bmatrix} \begin{bmatrix} E_x \\ E_y \\ E_z \end{bmatrix}$$

$$D_x = \varepsilon_{xx} E_x + \varepsilon_{xy} E_y + \varepsilon_{xz} E_z$$

$$D_y = \varepsilon_{yx} E_x + \varepsilon_{yy} E_y + \varepsilon_{yz} E_z$$

$$D_z = \varepsilon_{zx} E_x + \varepsilon_{zy} E_y + \varepsilon_{zz} E_z$$

# Electro-Optic Effect: Modulator



**Fig. 13.11a** Electro-optic phase modulation in LiNbO<sub>3</sub> crystal.

Modulation Index: 
$$\Delta\Phi_m = \frac{-\omega l r_{33} n_e^3 E_m}{2c}$$

# Suggested Reading

- Chapter 2 :Advanced Engineering Electromagnetics *by* Constantine A. Balanis
- Chapter 13: Fields and Waves in Communication Electronics *by* Simon Ramo